



UNIVERSITY  
OF TRENTO - Italy  
Department of Physics

1<sup>st</sup> Summer School of

## Interdisciplinary Research on Brain Network Dynamics

June 24-28, 2019

# Photonic Processing Unit - Acceleration of Neural Network Training Based on Analog Optical Crossbar Arrays

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Neuromorphic Devices and Systems Group

IBM Zurich GmbH

June 24, 2019



# Outlook

- Quick Start :
- Recap from yesterday: Status of today's Deep Neural Network processing
  - How to transfer the concept of analog crossbar arrays into optics (photonics)

- Part 1:
- Holographic weight storage and signal processing
  - Optical crossbar array: Weight processing operations
  - Analogy: Optical crossbar array  $\Leftrightarrow$  electrical crossbar array
  - Prior approach in free-space-optics
  - Integrated-optical solution
  - Short intermezzo: What is Si-photonics ?

- Part 2:
- Building blocks of analog integrated-optical crossbar array
  - Beam shaping and routing optics: simulation
  - Optical coupling between Si-photonics and GaAs: Simulation
  - Integration of photorefractive GaAs with Si-photonics

- Part 3:
- First experimental results:
    - Chip for Si-Photonics functionality test
      - Beam shaping and routing optics
      - Input vector setup unit
    - Proof of single synapse function in photorefractive bulk GaAs
    - Photorefractive storage medium

## Summary



# People Involved in this PPU Project



**Bert  
Offrein**



**Folkert  
Horst**



**me**



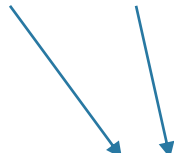
**Yannick  
Baumgartner**



**Efe  
Büyükozer**

## Recap from yesterday: Computational Challenge: Matrix-Vector Multiplications

Matrix-vector multiplications of the form


$$Wx = \begin{bmatrix} w_{0,0} & w_{0,1} & w_{0,2} & \dots & w_{0,N} \\ w_{1,0} & w_{1,1} & w_{1,2} & \dots & w_{1,N} \\ w_{2,0} & w_{2,1} & w_{2,2} & \dots & w_{2,N} \\ \vdots & \vdots & \vdots & \ddots & \vdots \\ w_{M,0} & w_{M,1} & w_{M,2} & \dots & w_{M,N} \end{bmatrix} \cdot \begin{bmatrix} x_0 \\ x_1 \\ x_2 \\ \vdots \\ x_N \end{bmatrix} = \begin{bmatrix} \sum_{i=0}^N w_{0,i} x_i \\ \sum_{i=0}^N w_{1,i} x_i \\ \sum_{i=0}^N w_{2,i} x_i \\ \vdots \\ \sum_{i=0}^N w_{M,i} x_i \end{bmatrix}$$

are common to the mentioned workloads and **dominate the computation time and energy consumption.**

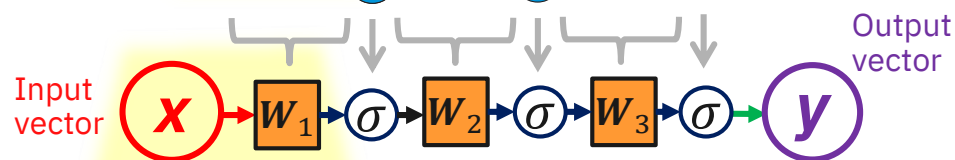
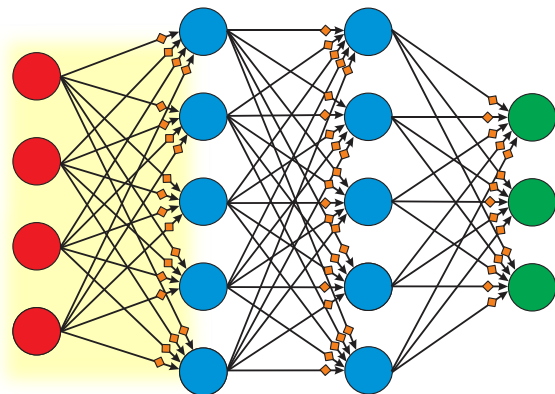
**Matrix-vector multiplications are “computationally expensive” !**

Our mission

Develop dedicated hardware (→ Analog Crossbar Arrays) which enables **efficient analog implementation of matrix-vector multiplications** and therefore acceleration of Deep Neural Network Learning

# Recap from yesterday: DNN Training by Backpropagation Algorithm

## Neural net as chain of vector operations:



$$W_1 x = \begin{bmatrix} w_{1,0,0} & w_{1,0,1} & \dots & w_{1,0,N} \\ w_{1,1,0} & w_{1,1,1} & \dots & w_{1,1,N} \\ \vdots & \vdots & \ddots & \vdots \\ w_{1,M,0} & w_{1,M,1} & \dots & w_{1,M,N} \end{bmatrix} \cdot \begin{bmatrix} x_0 \\ x_1 \\ \vdots \\ x_N \end{bmatrix} = \begin{bmatrix} \sum_{i=0}^N w_{1,0,i} x_i \\ \sum_{i=0}^N w_{1,1,i} x_i \\ \vdots \\ \sum_{i=0}^N w_{1,M,i} x_i \end{bmatrix}$$

Multiply

## Components:

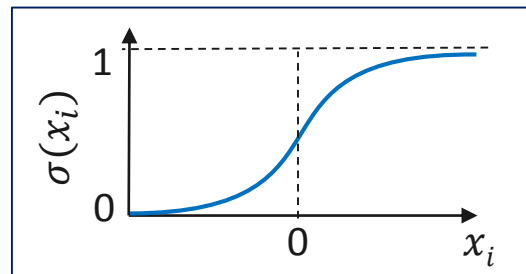
- Layers of neurons ● ● ● ●
- Synaptic interconnections

## Mathematical operations:

: Signal vector

: Synaptic weight matrix  $[W_n]$

: Per-element neural (non-linear) activation function (sigmoid):



# Recap from yesterday: Status of Today's Deep Neural Network Processing

Current situation

- Processing dominated by large matrix operations

Forward propagation:

$W$

Backward propagation:

$W^T$

Weight update:

$\Delta W$

Scale  $\propto N^2$   
Neurons/layer

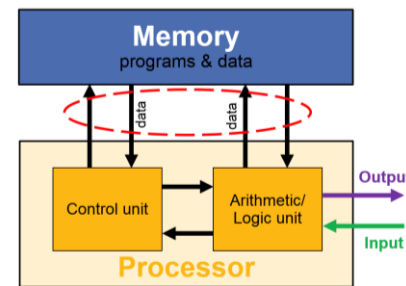
- Large training datasets: Thousands of training cases

- Inefficient on standard Von-Neumann architecture systems:

- (Mostly) Serial processing
- Low computation to IO ratio
- → Memory bottleneck



High performance computer



Today's standard computer architecture  
(→ proposal by John Von-Neumann in 1945)

Need for faster and more efficient DNN processing

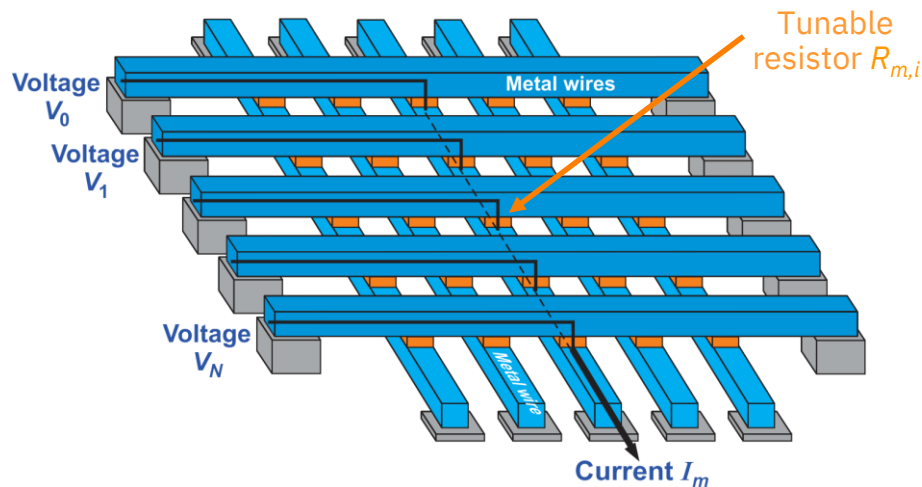
Borrow some concepts from the brain:

- Analog signal processing
- Fully parallel processing
- Tight integration of processing and memory

Analog Crossbar Arrays

# How to Transfer Concept of Analog Crossbar Arrays into Optics

Analog **electrical** crossbar array



Tunable resistors (with “memory”) ↔ Synaptic weights

Resistive Processing Unit (RPU)  
to accelerate processing of DNNs

Analog **optical** crossbar array  
Analog **photonic** crossbar array



???? ↔ Synaptic weights

Photonic Processing Unit (PPU)  
to accelerate processing of DNNs



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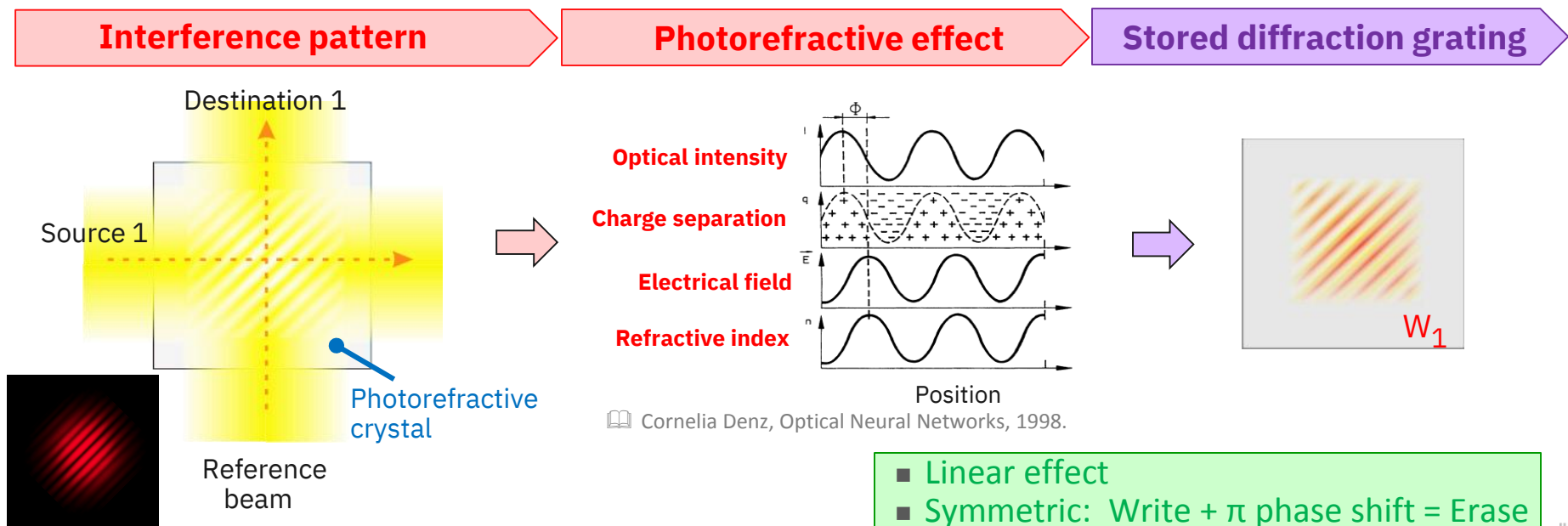


# Holographic Weight Storage and Signal Processing

- **Concept:** Synaptic connections are created as refractive index gratings in a photorefractive material

- **Photorefractive material:** ① Optically active electron traps + ② Pockels effect

⇒ Two interfering optical beams in photorefractive material can write a refractive index grating:



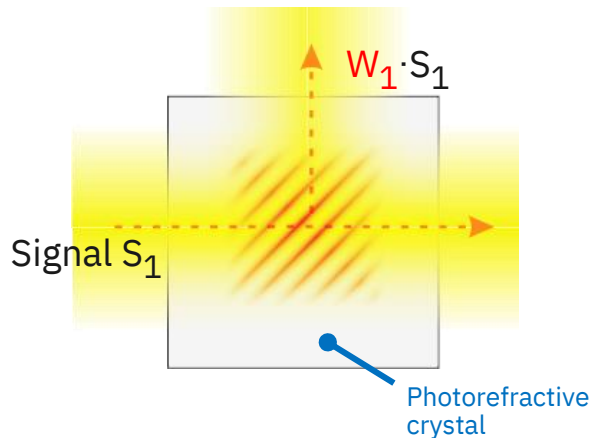
- Linear effect
- Symmetric: Write +  $\pi$  phase shift = Erase



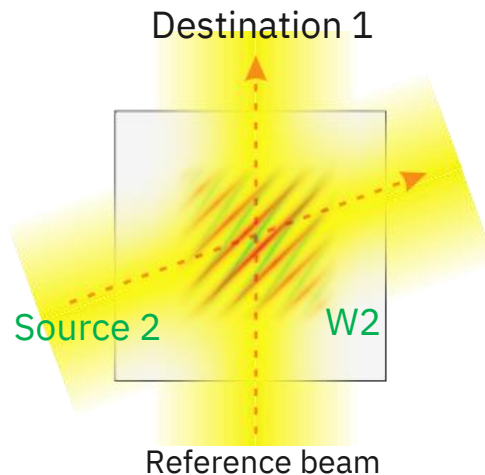
# Holographic Weight Storage and Signal Processing

## Synaptic weight processing:

Diffraction grating **readout**:

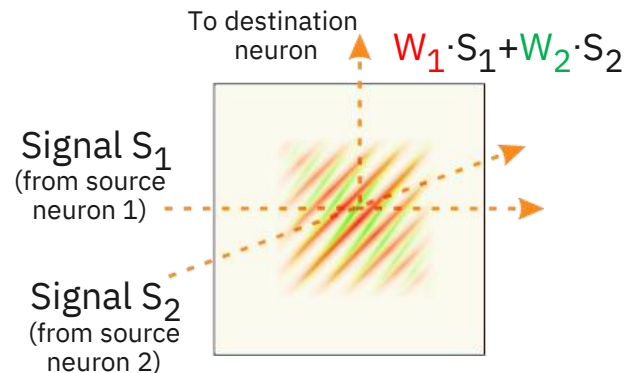


**Write a 2nd grating:**



**Readout** on two diffraction gratings:

**“Multiply & accumulate”**



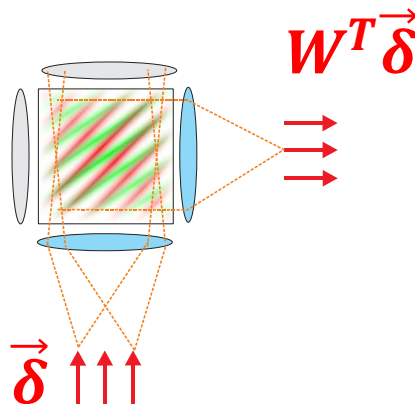
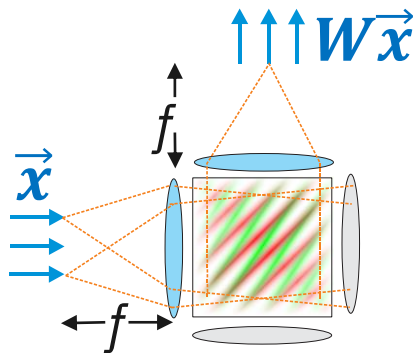
**Synaptic weight gratings diffract light from optical input beams to optical output beams**

- Source and destination neurons are encoded by different beam angles in the crystal
- There is a unique grating for every source - destination combination
- Optical signaling: Amplitude & Phase → **Bipolar signals and weights**

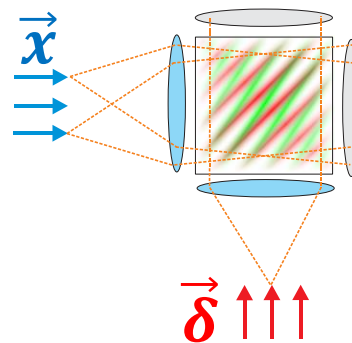
# Optical Crossbar Array: Weight Processing Operations

Interaction in the photorefractive medium uses collimated beams under different angles

- Add lenses around the medium for conversion to/from arrays of point sources or images:



$$\Delta W = -\eta \vec{x} \otimes \vec{\delta}$$



**All weight processing operations for neural network processing are supported**

# Analogy: Optical Crossbar Array $\Leftrightarrow$ Electrical Crossbar Array

Forward propagation  $\odot \rightarrow W$

Backward propagation  $\leftarrow W^T \odot \delta$

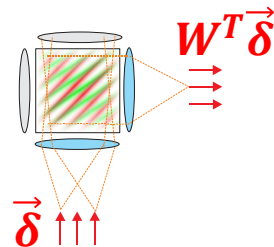
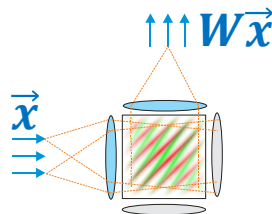
Synaptic weight update  $\odot \rightarrow \Delta W \leftarrow \delta$

Analog **optical** crossbar array

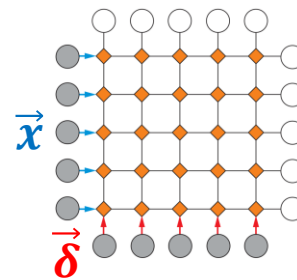
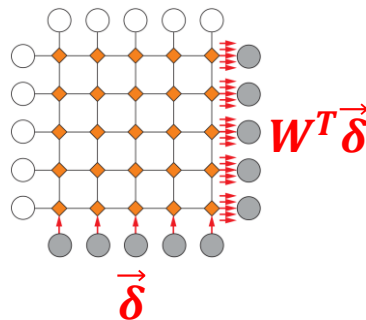
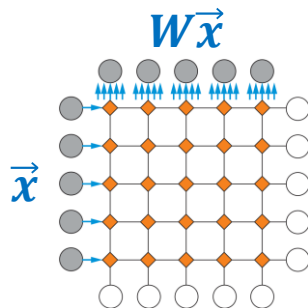
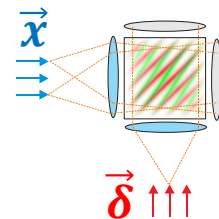
Optical waveguides  
Distributed weights  
Refractive index tuning

Resistance tuning  
Local weights  
Electrical wires

Analog **electrical** crossbar array



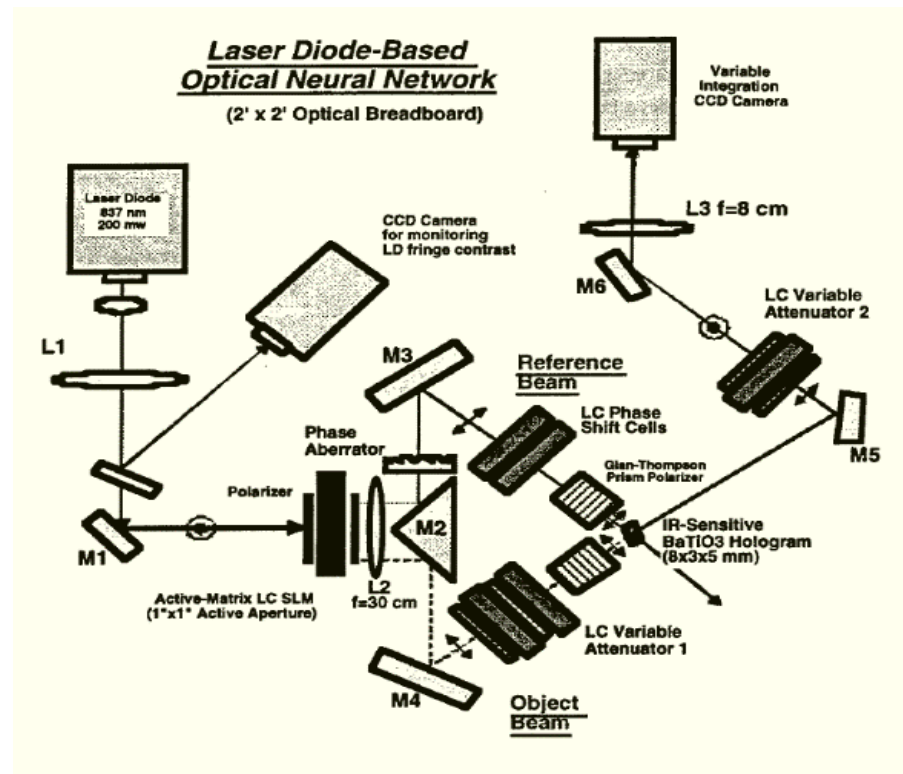
$$\Delta W = -\eta \vec{x} \otimes \vec{\delta}$$



# Optical Crossbar Array: Prior Approach in Free-Space-Optics

**Concept was demonstrated in the 90s using free-space optics:**

- Example: Hughes Research Laboratories
- Backpropagation training of Artificial Neural Networks shown
- Large optical breadboard setup, slow electro-optics



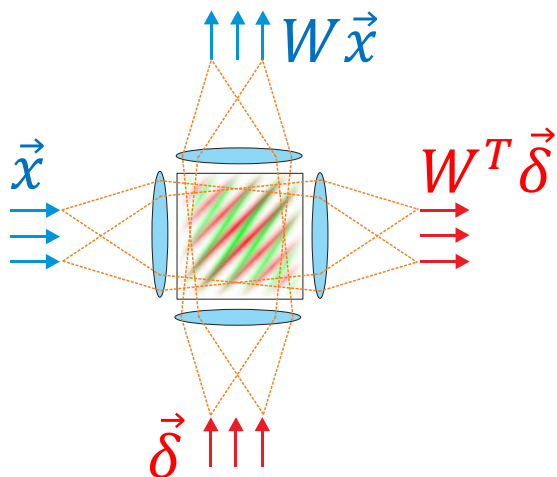
Yuri Owechko and Bernard H. Soffer, "Holographic neurocomputer utilizing laser diode light source", 1995

# Optical Crossbar Array: Integrated Solution

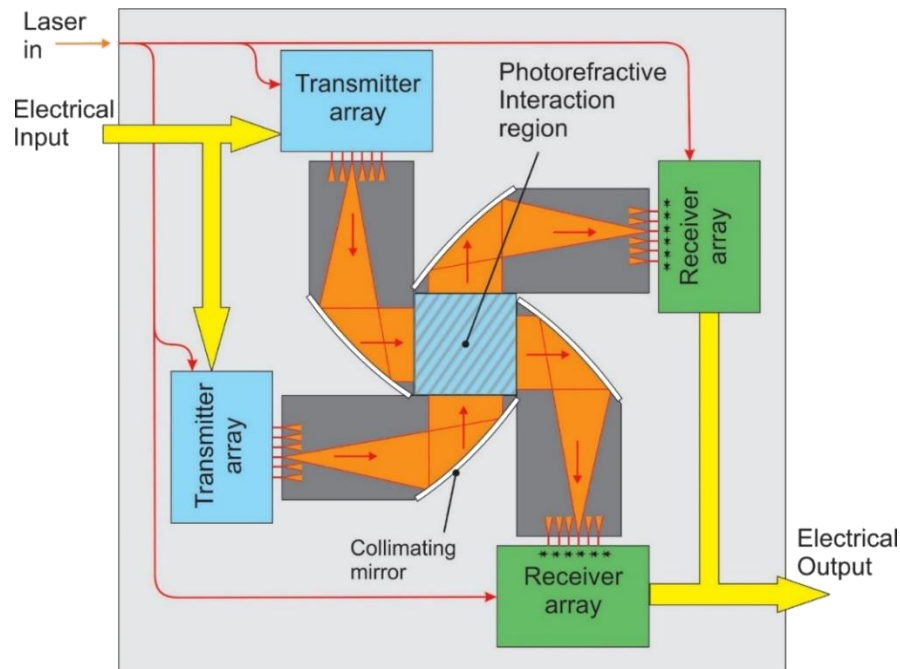
Our novel approach

## Miniaturize using Integrated Optics

- Electro-optic conversion and beam shaping optics **on a Silicon-Photonics (Si-Pho) chip**
- Memory: Photorefractive **thin film** on silicon

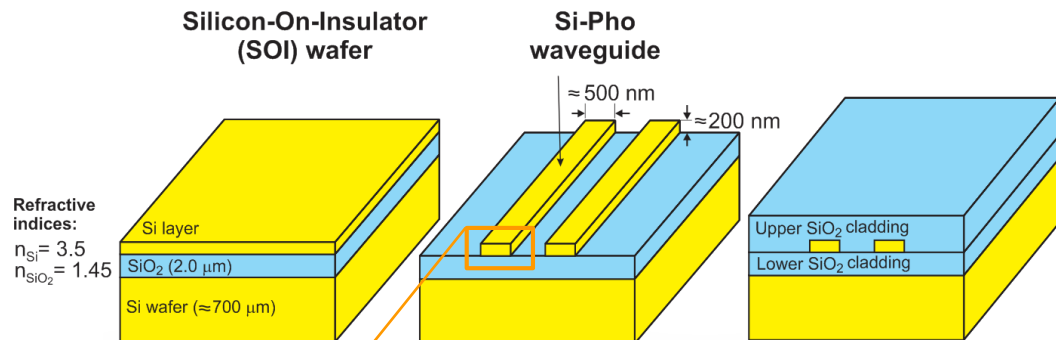


Schematic layout

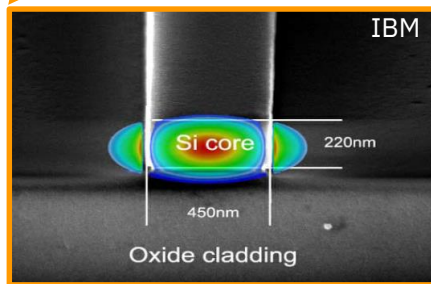


# Short Intermezzo: What is Si-Photonics ?

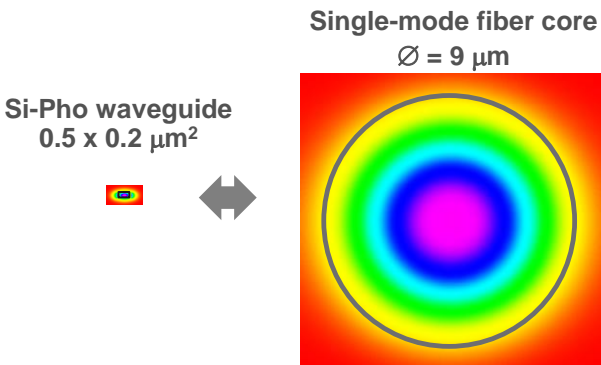
- **Silicon photonics (Si-Pho)** is the technology of photonic integrated systems which use silicon (Si) as light carrier medium
- Si-Pho technology exploits semiconductor fabrication techniques (CMOS-technology) established for electrical integrated circuits which also use Si as technology platform



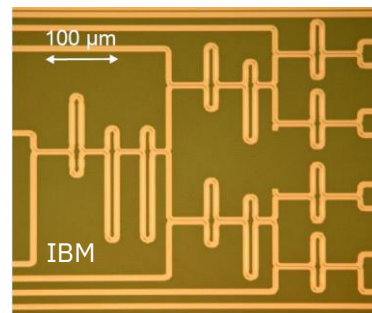
SEM image:  
Si-Pho waveguide facet



Micrograph of complex  
Si-Pho device:  
Cascaded Mach-Zehnder  
interferometers enabling  
wavelength filtering for WDM



Refractive index difference:  
 $n_{\text{core}} - n_{\text{cladding}} \approx 0.01$





# Outlook

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- Building blocks of analog integrated-optical crossbar array
  - Beam shaping and routing optics: simulation
  - Optical coupling between Si-photonics and GaAs: Simulation
  - Integration of photorefractive GaAs with Si-photonics



# Building Blocks of Analog Integrated-Optical Crossbar Array

## ▪ 2-dimensional and planar Si-photonics waveguides

### ▪ Beam shaping optics:

- Parabolic-shaped collimating mirrors
- Curved/tilted focal planes for aberration correction

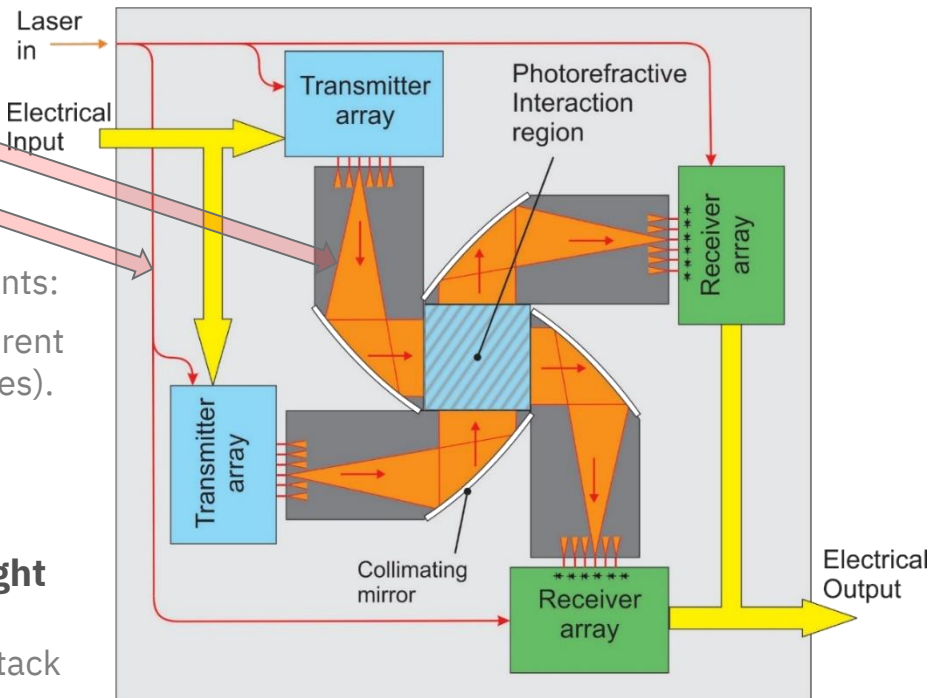
### ▪ Transmitter & receiver array

Standard Si-photonics modulators and detector components:

- Transmitter: Sets up the input vector as an array of coherent point light sources with adjustable intensities (and phases).
- Detector: Detects intensity (and phase) of the refocused output signals

### ▪ Photorefractive interaction region for synaptic weight storage

- III/V photorefractive material bonding to Si-photonics stack
- Overlap area for vertical directional coupling



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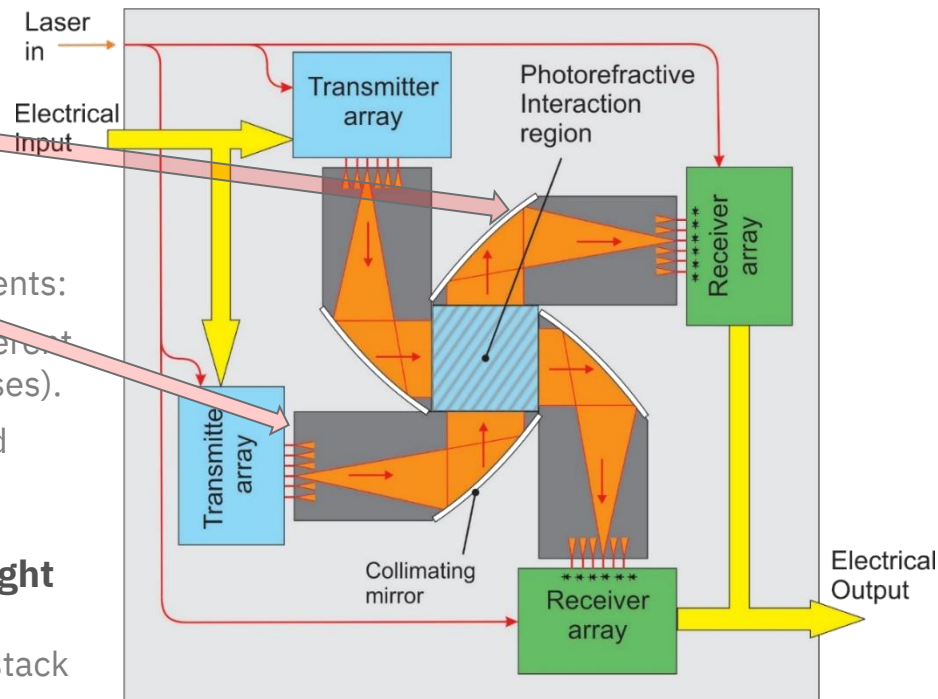
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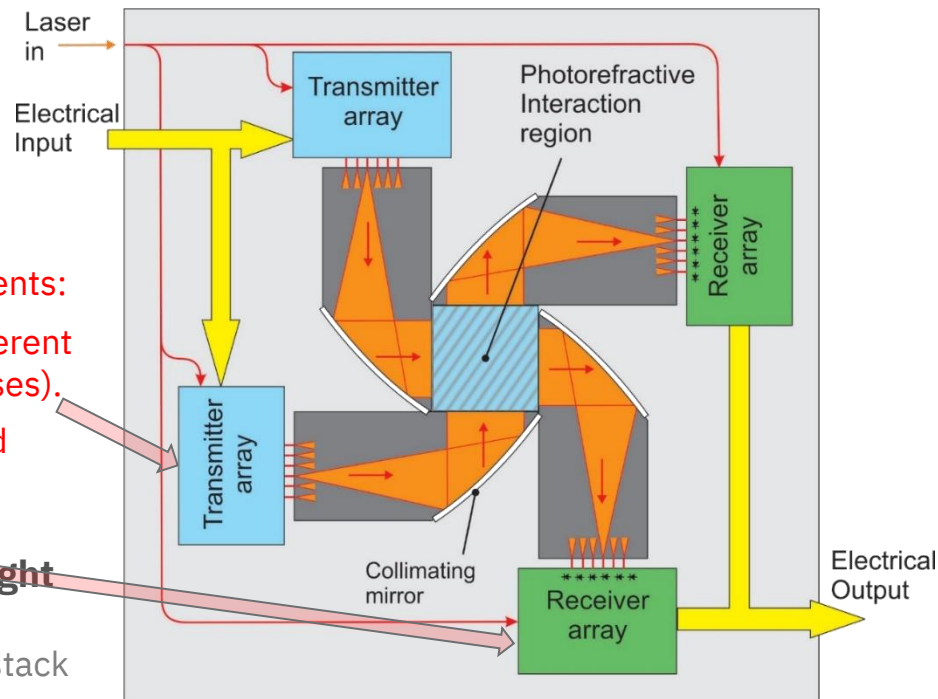
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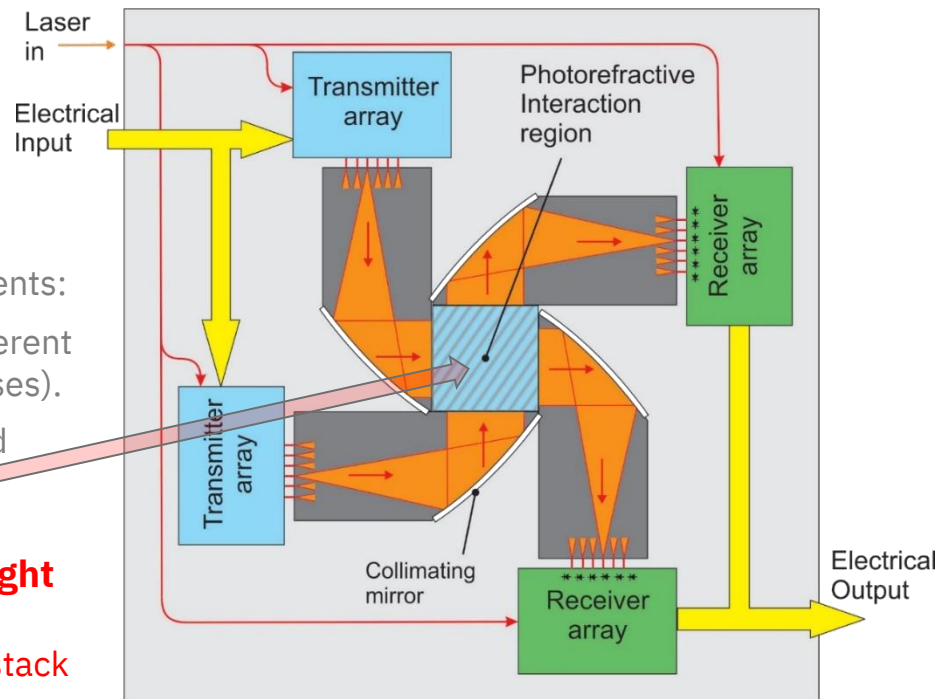
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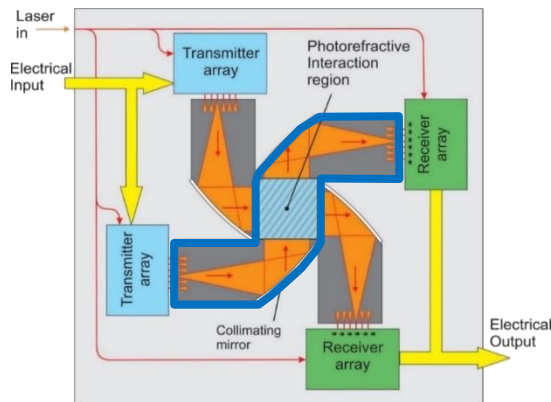
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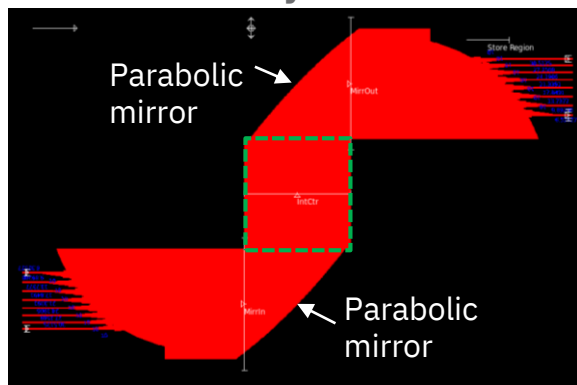
- III/V photorefractive material bonding to Si-photonics stack
- Overlap area for vertical directional coupling



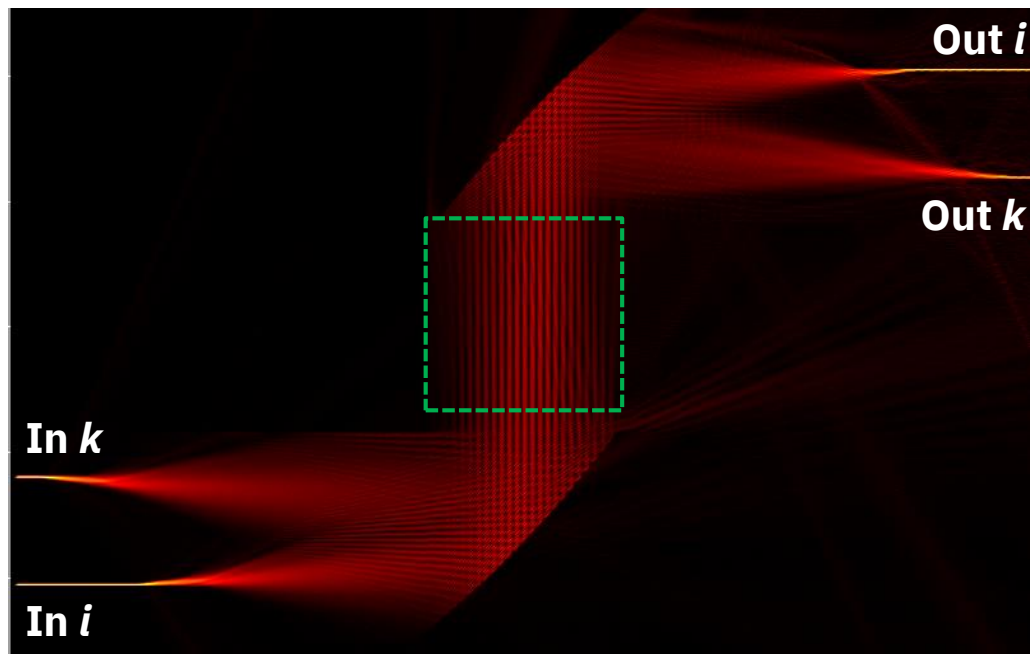
# Beam Shaping and Routing Optics: Simulation



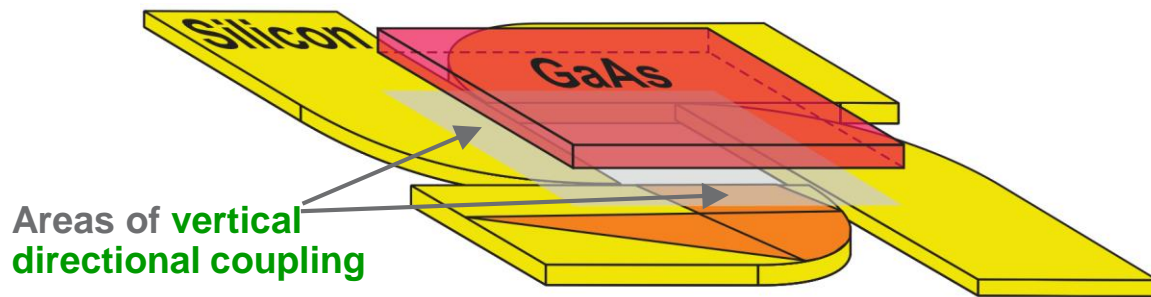
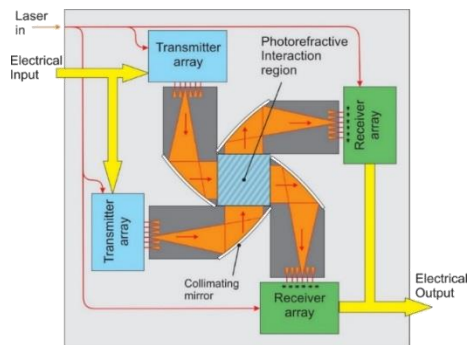
Layout



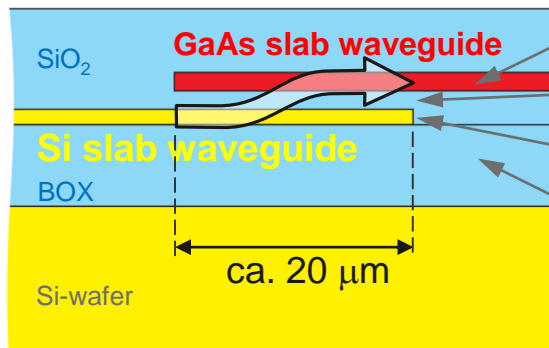
Simulated transmission



# Optical Coupling Between Si-Photonics and GaAs: Simulation



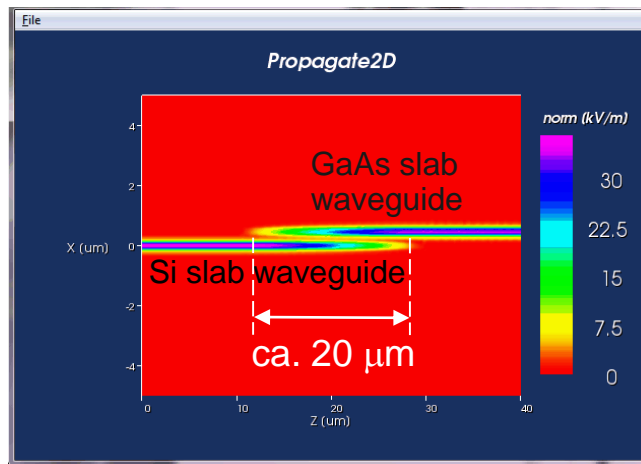
## Design



Layer thicknesses:

$t_{\text{GaAs-WG}} = 260 \text{ nm}$   
 $t_{\text{Gap}} = 180 \text{ nm}$   
 $t_{\text{Si-WG}} = 220 \text{ nm}$   
 $t_{\text{BOX}} = 2.0 \text{ μm}$

## Simulation result



Mode overlap calculation:  
**99.7%**



# Integration of Photorefractive GaAs with Si-Photonics

Metallo-Organic Chemical Vapor Deposition (MOCVD) of AlGaAs etch stop layer

MOCVD of semi-insulating photorefractive GaAs layer

Atomic layer deposition (ALD) of  $\text{Al}_2\text{O}_3$  bonding layer

GaAs wafer

Etch stop layer AlGaAs

GaAs wafer

Photorefractive GaAs (235 nm) AlGaAs

GaAs wafer

Bonding layer  $\text{Al}_2\text{O}_3$  GaAs AlGaAs

GaAs wafer

E-beam lithography and dry etching of Si-waveguides

Deposition of upper  $\text{SiO}_2$  cladding

Chemical mechanical polishing (CMP)

Atomic Layer Deposition (ALD) of  $\text{Al}_2\text{O}_3$  bonding layer

Wafer bonding

Si-layer (220 nm)

BOX ( $\text{SiO}_2$ , 2.0  $\mu\text{m}$ )

Si-wafer

Si-photonics waveguides

BOX

Si-wafer

$\text{SiO}_2$

BOX

Si-wafer

$\text{SiO}_2$

BOX

Si-wafer

$\text{Al}_2\text{O}_3$

$\text{SiO}_2$

BOX

Si-wafer

Wafer bonding

Grinding and wet-etching of GaAs backside wafer

Wet-etching of AlGaAs etch-stop layer

Patterning of GaAs with e-beam lithography and dry-etching

Deposition of  $\text{SiO}_2$  upper cladding

W- and Al- deposition and patterning of electrical heaters and leads

GaAs wafer

Etch stop layer AlGaAs

Photorefractive GaAs

GaAs slab waveguides

$\text{SiO}_2$  upper cladding

Electrical heaters and leads

$\text{SiO}_2$

BOX

Si-wafer

$\text{SiO}_2$

BOX

Si-wafer

$\text{SiO}_2$

BOX

Si-wafer

$\text{SiO}_2$

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Si-wafer

$\text{SiO}_2$

BOX

Si-wafer

$\text{SiO}_2$

BOX

Si-wafer



# Outlook

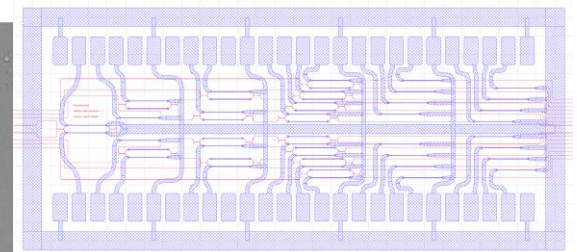
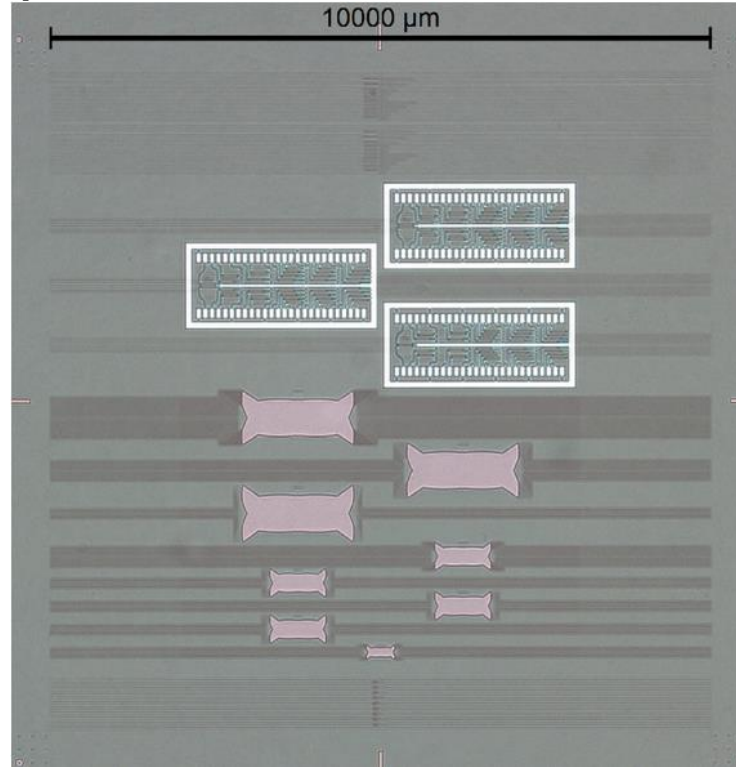
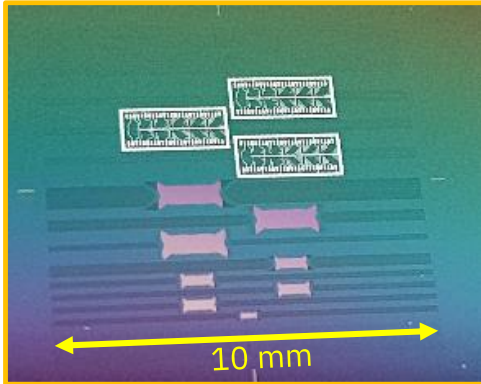
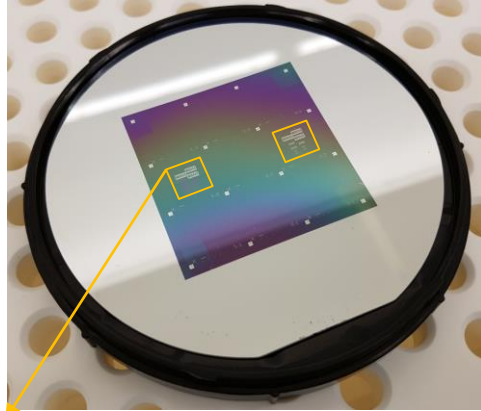
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- First Experimental Results:
  - Chip for Si-Photonics functionality test
    - Beam shaping and routing optics
    - Input vector setup unit
  - Proof of single synapse function in photorefractive bulk GaAs
  - Photorefractive storage medium

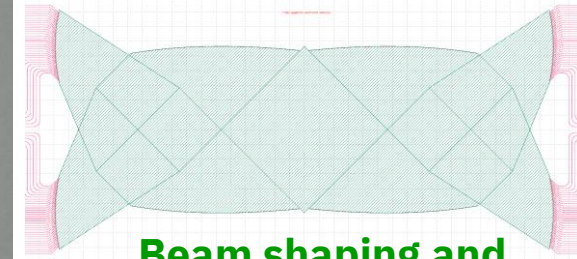


# First Experimental Results: Chip for Si-Photonics Functionality Test

Photograph of realized test chip



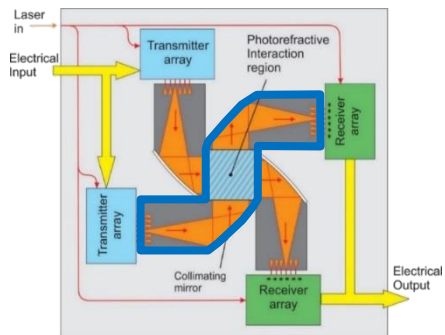
Input vector setup unit



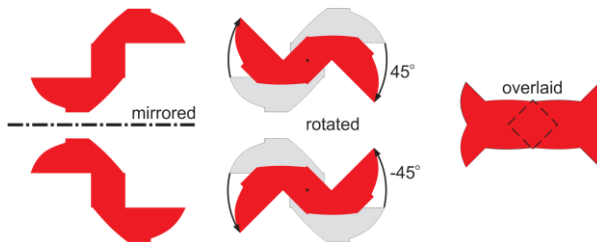
Beam shaping and routing optics



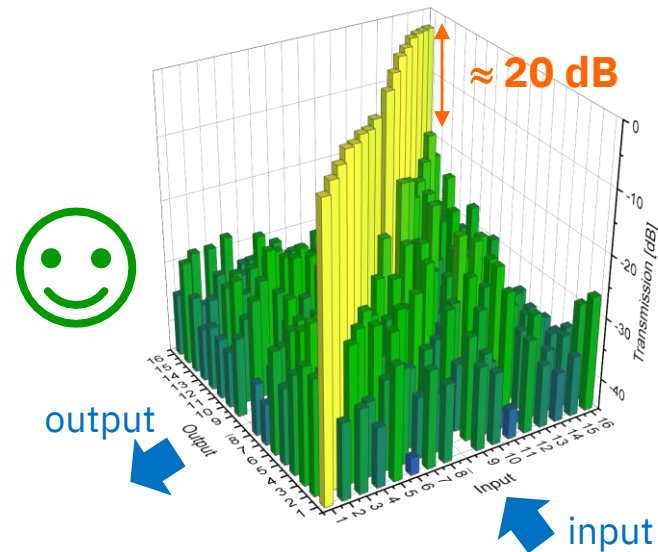
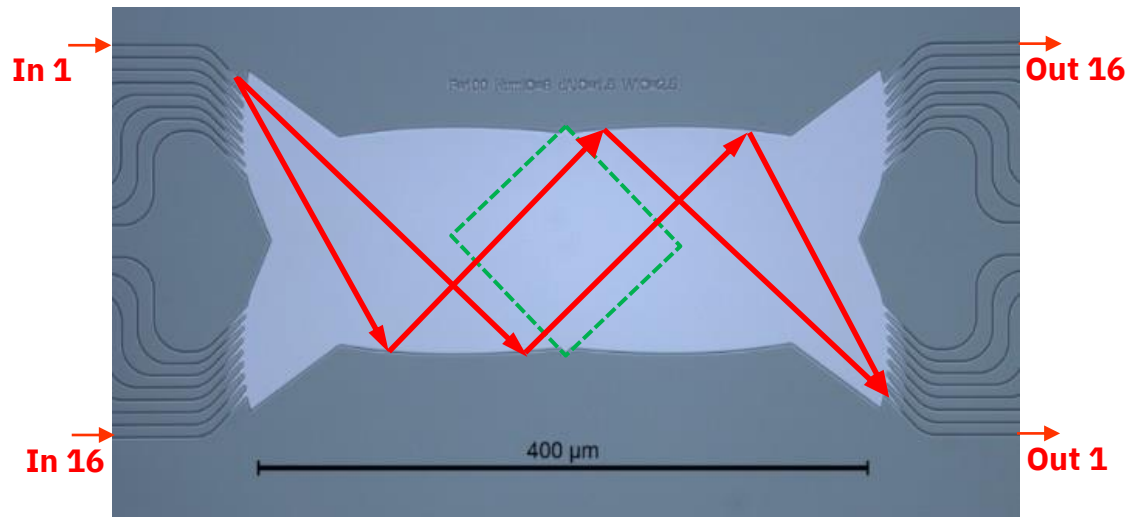
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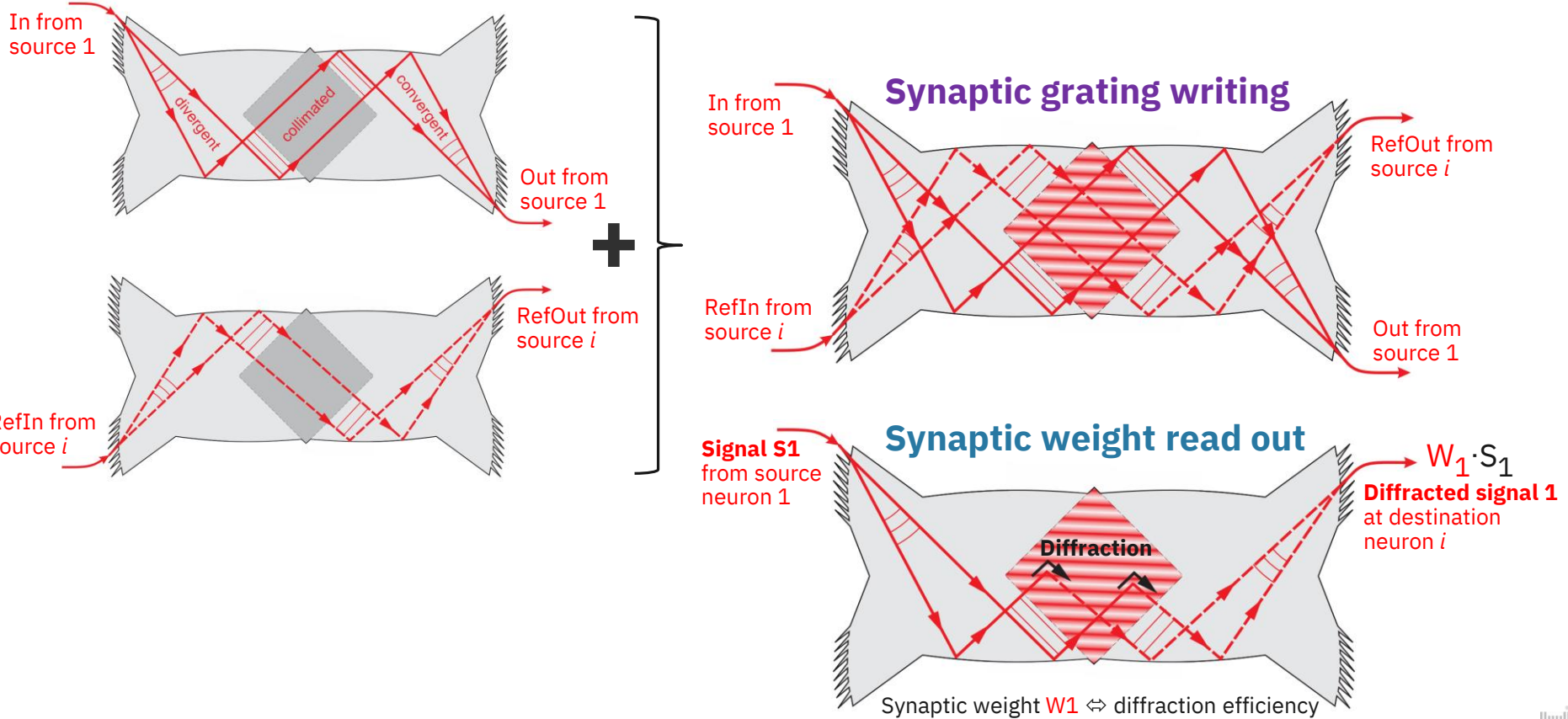
Slightly modified structure to test Si-photonics functionality



Experimental result of transmission matrix:

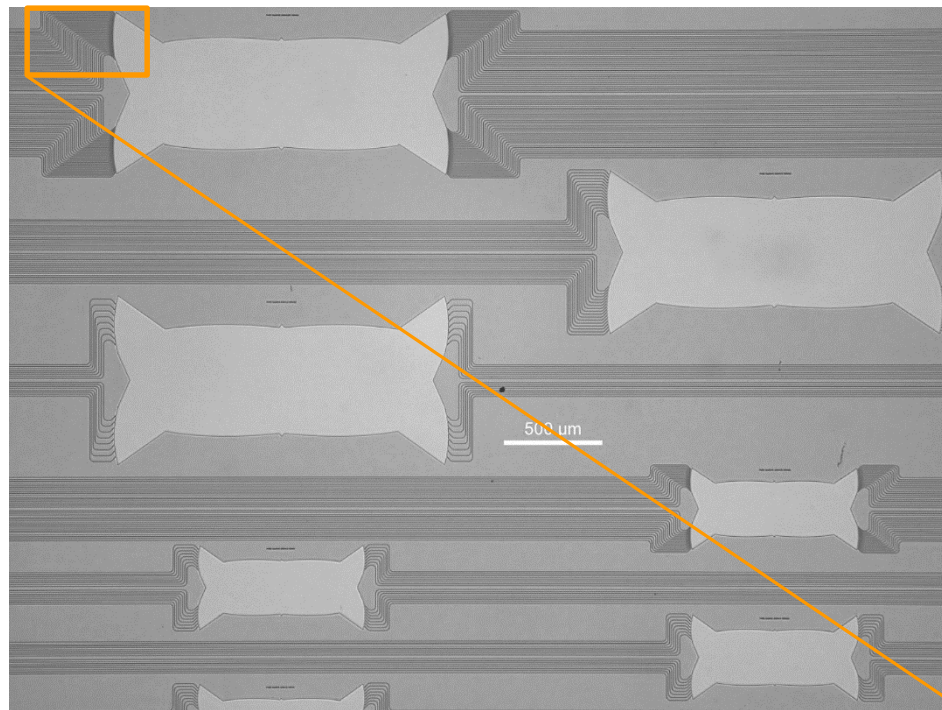


# Beam Shaping and Routing Optics

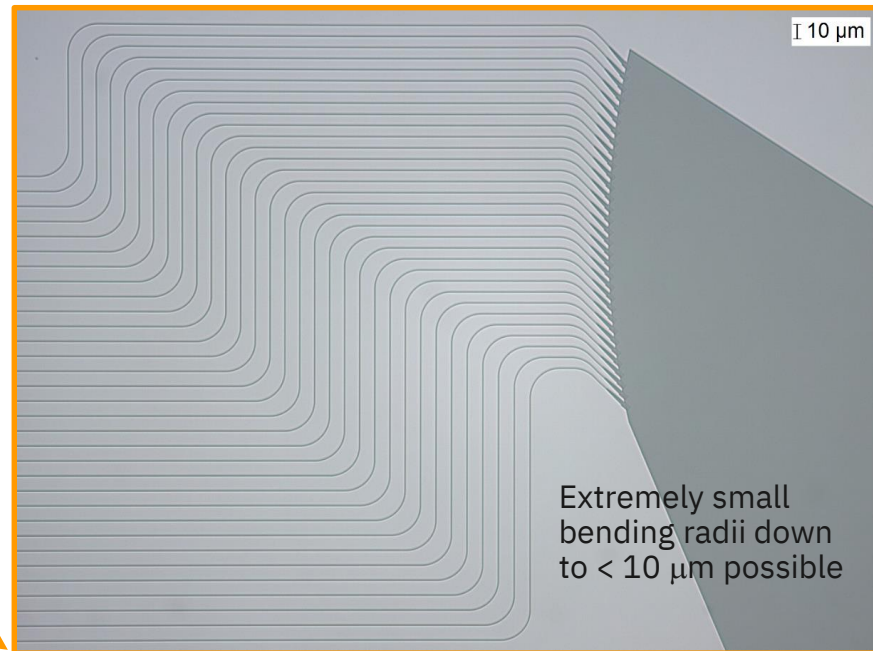




# Beam Shaping and Routing Optics



**2 x 32 Inputs → 2 x 32 Outputs**

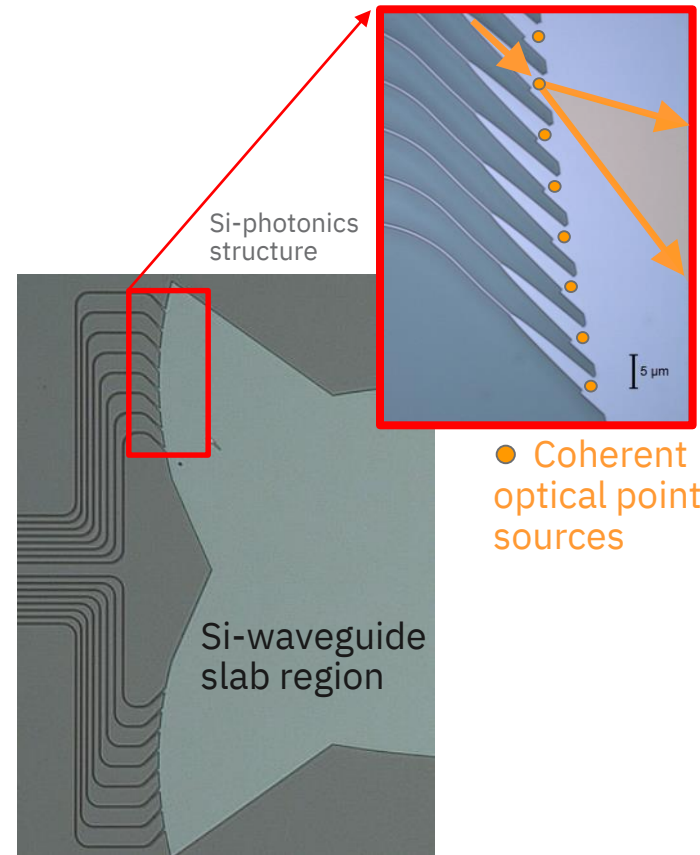
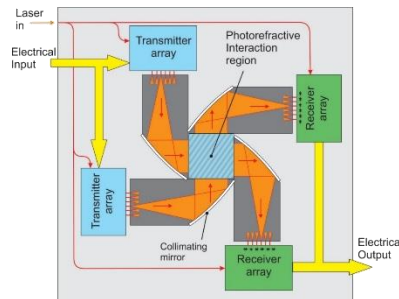
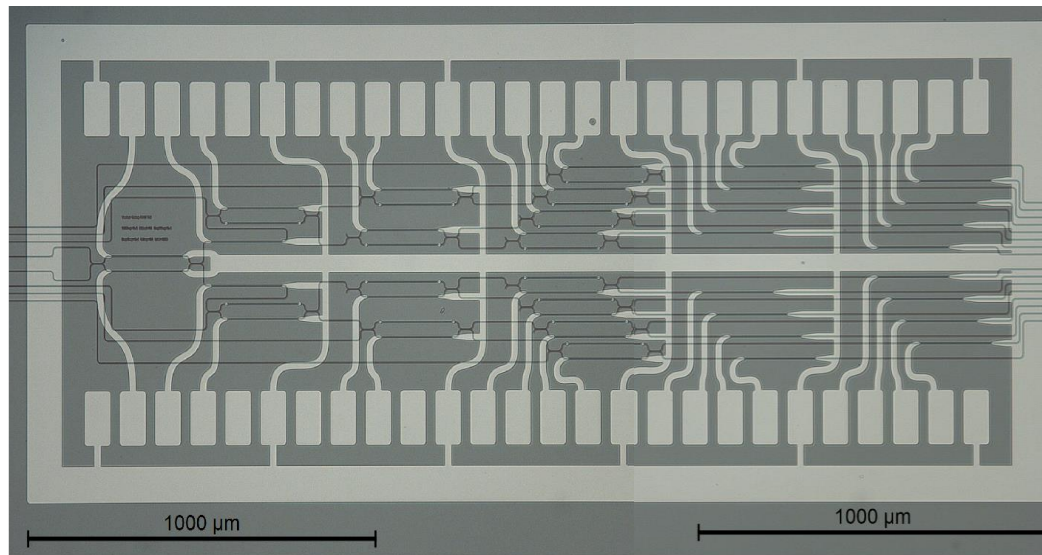


# Input Vector Setup Unit

## Task of input vector setup unit:

Encoding electrical signals onto the transmitter array of coherent optical point sources.

Micrograph of input vector setup unit

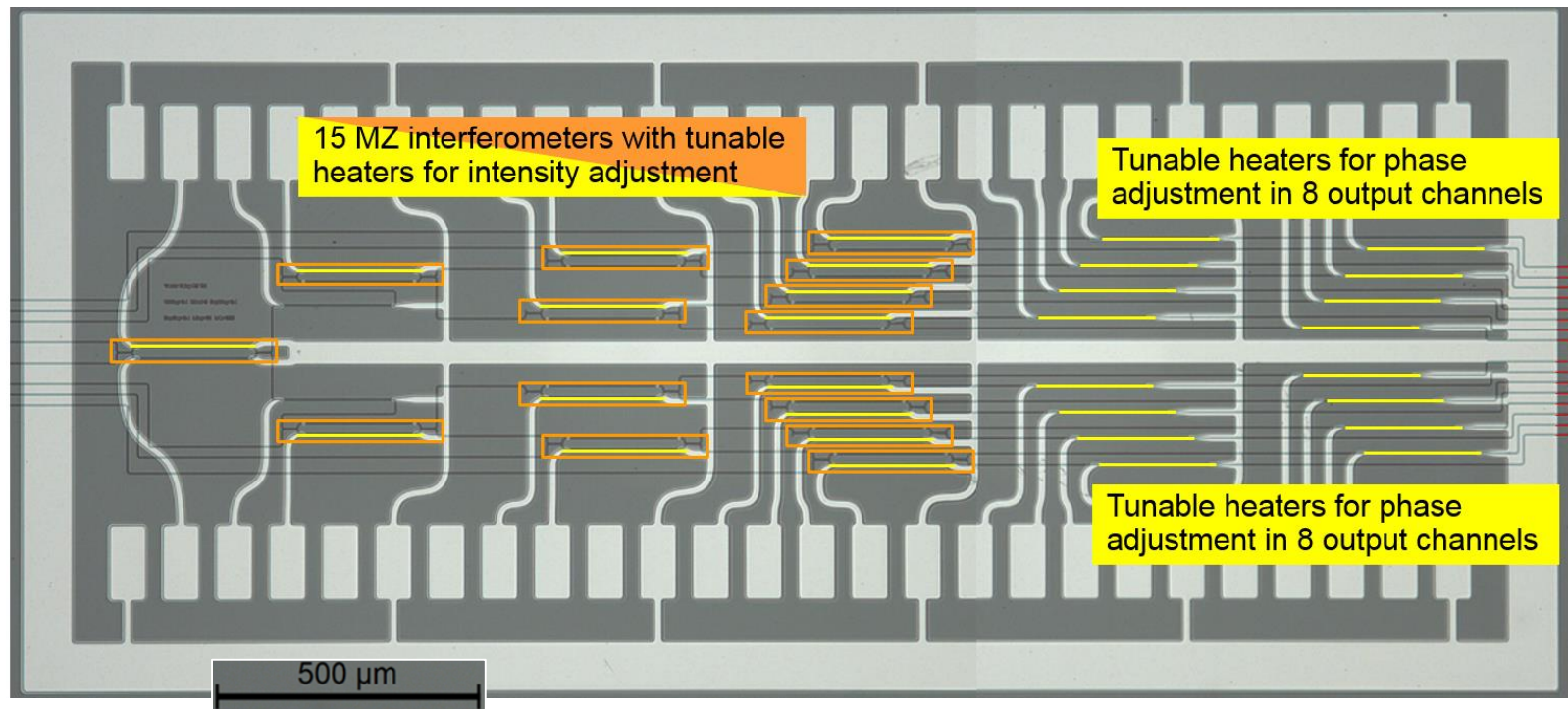




# Input Vector Setup Unit

## Micrograph of complete unit comprising:

- 15 ( $= 1 + 2 + 4 + 8$ ) Mach-Zehnder interferometers with tunable heaters for individual intensity adjustment
- 2 x 8 tunable heaters for individual phase adjustment

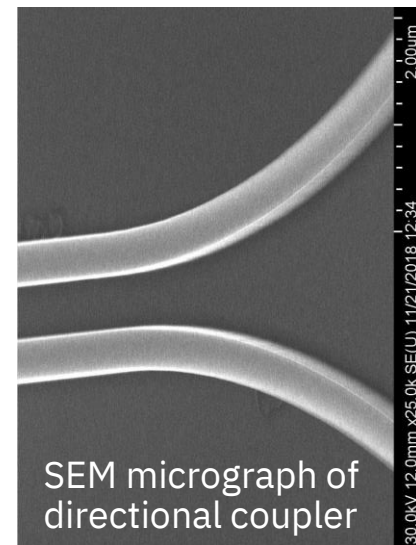
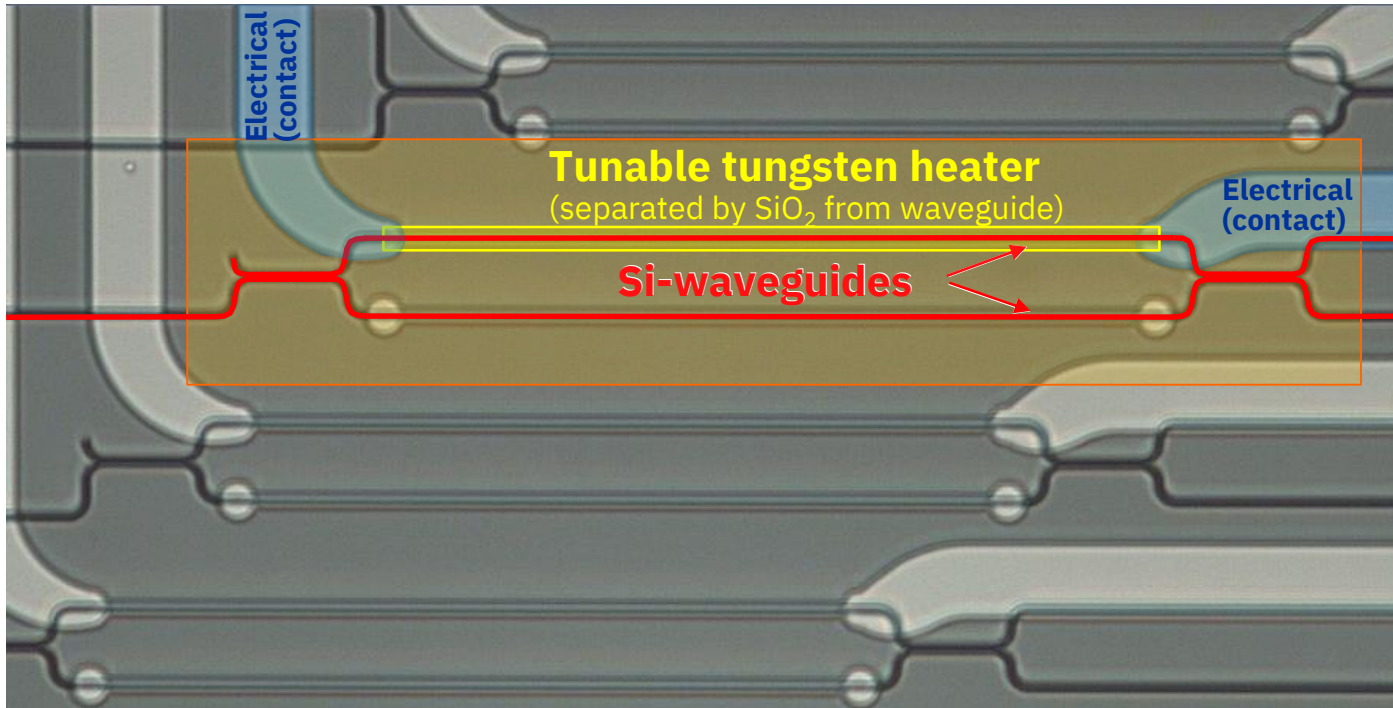


2 x 8 outputs  
independently  
adjustable in  
intensity and  
phase

# Input Vector Setup Unit

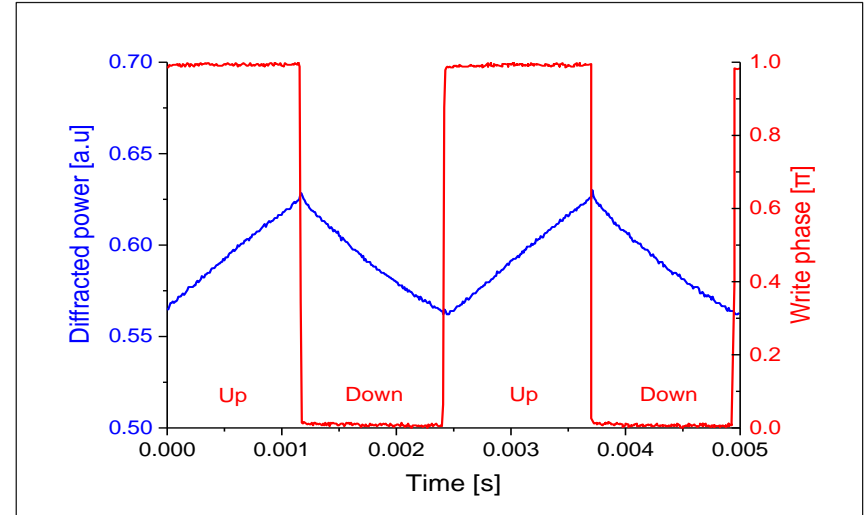
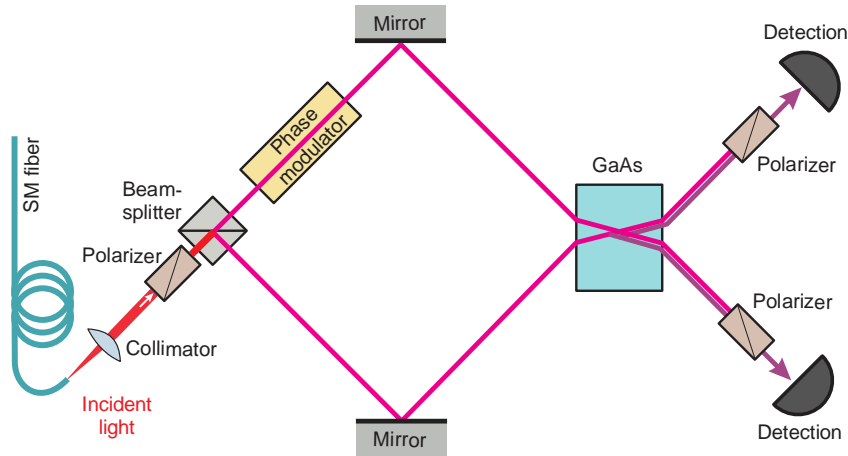
**Micrograph of Mach-Zehnder interferometers (each) comprising:**

- 2 interferometer waveguide arms (one arm with tungsten heater for tuning phase changes)
- 2 directional couplers for (50:50 splitting and combining)



# Proof of Single Synapse Function in Photorefractive Bulk GaAs

Two-wave mixing in bulk GaAs crystal  $\approx$  single synapse:



📖 P. Yeh, “Two-Wave Mixing in Nonlinear Media”  
doi: 10.1109/3.18564



**Control of photorefractive weight:**

- **Smooth slopes: analog behavior**
- **Symmetric**

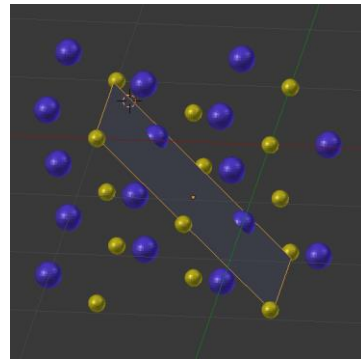
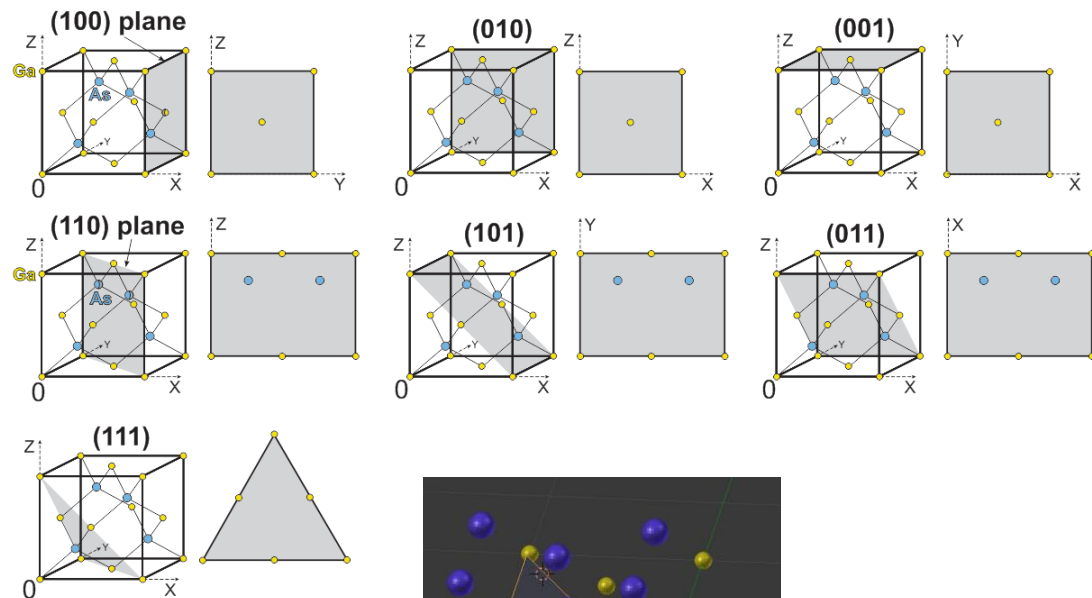
**Next step: Reproduce in thin GaAs film**



# Photorefractive Storage Medium: First Results

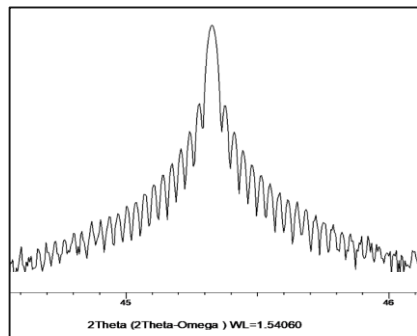
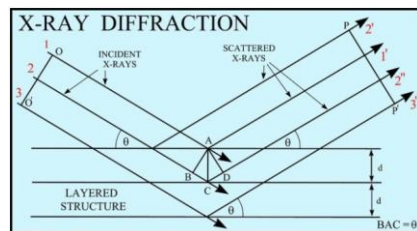
## Thin film of semi-insulating GaAs

- MOCVD growth, optimized for:
  - 110 substrate:
    - ⇒ Correct orientation of Pockels tensor
  - As-rich growth → “EL2” Deep traps
- Material alternatives would be:
  - GaAs:Cr
  - InP:Fe
  - BaTiO<sub>3</sub>

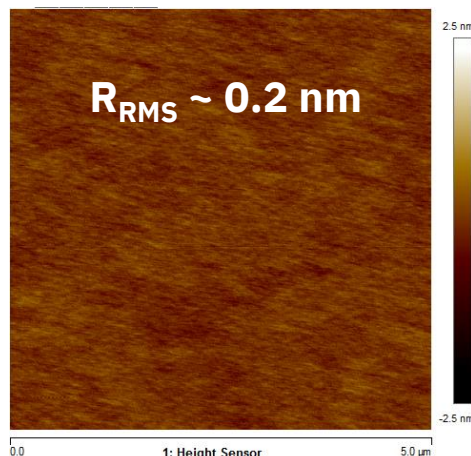


# Photorefractive Storage Medium: First Results

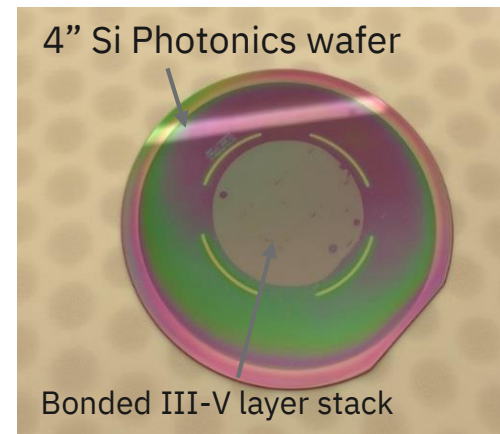
- Analysis of grown GaAs layers by means of **XRD** (X-Ray Diffraction):



- Roughness measurement result obtained with **AFM**:



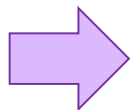
- **Wafer bonding** of 2" GaAs wafer onto 4" Si photonics wafer



# Photorefractive Storage Medium: Current Status

## Results:

- **Epitaxial layer growth**
  - Good crystalline quality
  - Smooth surface
  - Bonds well to  $\text{SiO}_2$  on Si
- **Semi-insulating layer**
- **But: Strong optical absorption**
  - Because concentration too high



**Next step:**

Fine-tuning of EL2 trap concentration



# Summary

- **Our group mission:**
  - Research for Artificial Intelligence (AI)
- **Our strategy in the Photonic Processing Unit project:**
  - Exploitation of our **Si-photonics** expertise for neuromorphic computing hardware development
- **Our project:**
  - Realization of integrated analog optical crossbar arrays for speed-up of computationally “expensive” matrix-vector multiplications in deep neural network processing
- **Our main tasks:**
  - Demonstration of analog synaptic weight storage in photorefractive semi-insulating thin GaAs layers
  - Realization of Si-photonics chip containing all building blocks to show NxN crossbar array operation
- **Our current status:**
  - Correct functioning of major Si-photonics building blocks demonstrated
  - Photorefractive effect in semi-insulating GaAs bulk material demonstrated
  - Wafer bonding of GaAs to Si-photonics demonstrated
  - MOCVD based epitaxial growth of semi-insulating thin GaAs layers demonstrated
  - Tuning of GaAs growth process with correct EL2 trap concentration for achieving suitable photorefractivity and low optical propagation loss is ongoing